APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY THIRD SEMESTER M. TECH DEGREE EXAMINATION Electronics & Communication Engineering (Telecommunication Engineering) 04EC7809—RF MEMS

Max. Marks: 60

Duration: 3 Hours

PART A

Answer All Questions

Each question carries 3 marks

- 1. Discuss the characteristics of RF MEMS devices?
- 2. Describe testing of RF MEMS?
- 3. Discuss the process of bulk micromachining?
- 4. Explain piezoelectric actuation mechanism in MEMS.?
- 5. Draw series and shunt cantilever type RF MEMS switch.?
- 6. List various types of MEMS capacitors?
- 7. Discuss gap tuning and area tuning capacitors in MEMS?
- 8. Draw different T Line based tunable matching network?

PART B

Each question carries 6 marks

9. Discuss with neat diagram front end design of 3-band wireless telephone system?

OR

- 10. Describe RF MEMS in phased arrays?
- 11. Discuss various actuation mechanisms in MEMS?

OR

OR

- 12. Describe bulk micromachining technique in MEMS?
- 13. Illustrate RF FEED Via for On wafer hermetic packaging of MEMS switch?

- 14. Draw and explain RF MEMS Switch design in detail?
- 15. Discuss electromechanical FEM modelling of RF switch?

OR

- 16. Explain the Fabrication of MEMS Ohmic switch?
- 17. Explain MEMS piezoelectric varactors in detail?

OR

- 18. Explain the tuning of Toroidal meander type inductors in detail?
- 19. Explain the reconfigurable patch antenna array using MEMS switch?

OR

20. Discuss the application of MEMS resonator as an oscillator?